

# 产品规格说明书

**Product Data Sheet** 

# AOS4GT32xx

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逻辑器件

も源管理IC 通信接口芯片











MOSFETs

运算放大器

显示驱动

MCU单片机

光电器件

#### AOS4GT32 Quadruple 2-Input Positive-OR Gate

#### **DESCRIPTIONS**

The AOS4GT32 Quadruple 2-input positive-OR gate is designed for  $\underline{2.0V}$  to 5.5V V $_{CC}$  operation. The AOS4GT32 device performs the Boolean function Y=A + B or Y=  $\overline{A} \cdot \overline{B}$  in positive logic. The device is fully specified for partial-power-down applications using  $I_{OFF}$ .

The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AOS4GT32 is available in Green SOP14 and TSSOP14 packages. It operates over an ambient temperature range of  $-40\,^{\circ}\text{C}$  to  $+125\,^{\circ}\text{C}$ .

#### **FEATURES**

Operating Voltage Range: 2.0V to 5.5V

Low Power Consumption: 1µA(Max)

Operating Temperature Range: -40°C to +125°C

TTL Input are Compatible

Output Drive:  $\pm 32$ mA at Vcc=5.0V

Ioff Supports Partial-Power-Down Mode Operation

Micro SIZE PACKAGES: SOP14, TSSOP14

#### LOGIC SYMBOL

# А В У

#### **APPLICATIONS**

AV Receiver

Blu-ray Player and Home Theater Digital Picture Frame(DPF)

High-Speed Data Acquisition and

Generation

Personal Navigation Device(GPS)

Portable Media Player

#### Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
100 1CT22	S0P14	8.65mm×3.90mm
A0S4GT32	TSSOP-14	5.00mm×4.40mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### **FUNCTION TABLE**

I NP	OUTPUT	
Α	В	Υ
Н	Н	Н
L	Н	Н
Н	L	Н
L	L	L

Y=A B H=High Voltage Level L=Low Voltage Level



AOS4GT32

#### PACKAGE/ORDERING INFORMATION(1)

PRODUCT	ORDERI NG NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE Marking <sup>(2)</sup>	MSL(3)	PACKAGE OPTION
AOS4GT32	AOS4GT32XP	-40℃~+125℃	SOP14	AOS4GT32	MSL3	Tape and Reel, 4000
AU340132	AOS4GT32XQ	-40℃~+125℃	TSSOP-14	AOS4GT32	MSL3	Tape and Reel, 4000

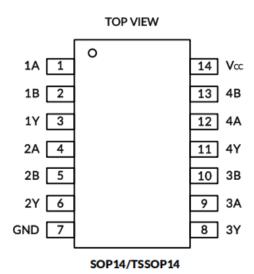
#### NOTE:

- (1) This information is the most current data available for the designated devices. This data is subject to change without noticeand revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
- (2) There may be additional marking, which relates to the lot trace code information(data code and vendor code), the logo or the environmental category on the device.
- (3) MSL, The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.

(1) I = i nput, 0 = output.



#### PIN CONFIGURATIONS



#### PIN DESCRIPTION

PIN SOP14/TSSOP-14	NAME	I/O TYPE <sup>(1)</sup>	FUNCTI ON
1	1A	I	Channel 1 logic input
2	1B	I	Channel 1 logic input
3	1Y	0	Logic level output 1
4	2A	I	Channel 2 logic input
5	2B	I	Channel 2 logic input
6	2Y	0	Logic level output 2
7	GND	-	Ground
8	3Y	0	Logic level output 3
9	3A	I	Channel 3 logic input
10	3B	I	Channel 3 logic input
11	4Y	0	Logic level output 4
12	4A	I	Channel 4 logic input
13	4B	I	Channel 4 logic input
14	Vcc	_	Power Supply

<sup>(1)</sup> I=input, O=output, P=power, G= Ground.

### Specifications Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
Vcc	Supply voltage range		-0.5	6.5	
Vı	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
V <sub>0</sub>	Voltage range applied to any output in the high power-off state <sup>(2)</sup>	n-impedance or	-0.5	6.5	
V <sub>0</sub>	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>				
Тік	Input clamp current		-50		
<b>І</b> ок	Output clamp current	V <sub>0</sub> <0		-50	
Ιo	Continuous output current			± 50	mA
	Continuous current through V∞ or G	ND		± 100	
JA	Package thermal impedance <sup>(4)</sup>	SOP14		105	°C/W
JA.	r dokago thermal rimpedance	TSSOP-14		90	
TJ	T <sub>J</sub> Junction temperature <sup>(5)</sup>			150	°C
Tstg	Storage temperature	-65	150		

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of Vcc is provided in the *Recommended Operating Conditions* table.
- (4) The package thermal impedance is calculated in accordance with JESD-51.
- (5) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $R_{JA}$ , and  $T_{A}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} T_A) / R_{JA}$ . All numbers apply for packages soldered directly onto a PCB.



### **ESD Ratings**

			VALUE	UNIT
		Human-body model (HBM), MIL-STD-883K METHOD 3015.9	± 2000	
V(ESD)	Electrostatic discharge	Charged-device model (CDM), ANSI/ESDA/JEDEC JS-002-2018	± 1000	V
		Machine Model (MM), JESD22-A115C(2010)	± 200	



#### ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (TYP values are at  $T_A=+25\,^{\circ}\text{C}$ , Full=-40 $^{\circ}\text{C}$  to 125 $^{\circ}\text{C}$ , unless otherwise noted.)

### Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply Voltage	<b>V</b> cc	Operating	2.0	5.5	
		Vcc=2. OV	1.0		
High-Level Input Voltage	Vih	Vcc=3.3V	1.5		
		Vcc=4.5V to 5.5V	2.0		
		Vcc=2. OV		0.3	V
Low-Level Input Voltage	VIL	Vcc=3.3V		0. 55	
		Vcc=4.5V to 5.5V		0.8	
Input Voltage	Vı		0	5.5	
Output Voltage	Vo		0	Vcc	
Input Transition Rise or Fall	t/ v	Vcc=2.0V to 5.5V		5	ns/V
Operating Temperature	Та		-40	125	$^{\circ}$ C

(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.

#### DC Characteristics

P#	ARAMETER	CONDI TI ONS	Vcc	TEMP	MI N <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
		I он=-100 µ А	2.0V to 5.5V		Vcc-0. 1			
		$I_{OH} = -8mA$	2. 0V		1.6			
	Voh	I он=-24mA	3. 3V		2.5			
	<b>V</b> 0H		4. 5V		3.8			
		$I_{OH} = -32mA$	5V		4. 2			
			5. 5V		4.8			V
		I он=100µ A	2.0V to 5.5V				0.1	V
		I он=8mA	2. 0V	Full			0.45	
	$V_{OL}$	I oH=24mA	3. 3V				0.55	
	<b>V</b> 0L		4.5V				0.55	
		I oH=32mA	5V				0.5	
			5. 5V				0. 45	
	A or	V F FV on CND	0V +o F FV	+25℃		± 0. 1	± 1	
Ιı	Binputs	V <sub>1</sub> =5.5V or GND	0V to 5.5V	Full			± 5	
		V V -5 -5V	0	+25℃		± 0. 1	± 1	
	off	V1 or V0=5.5V	0	Full			± 10	μA
				+25℃		0.1	1	
I cc		$V_1=5.5V$ or GND, $I_0=0$	2.0V to 5.5V	Full			10	
One input at 3 Other inputs at Vo		One input at 3.4V, Other inputs at Vcc or GND	5. 5V	Ful I			500	
C <sub>i</sub> Cap	(Input acitance)	Vcc=0V, f=10MHz	OV	+25℃		6		pF

- (1) All unused inputs of the device must be held at VCC or GND to ensure proper device operation.
- (2) Limits are 100% production tested at  $25^{\circ}$ C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

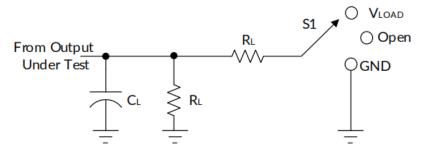
#### AC Characteristics

PARAMETER	SYMBOL	TEST CONDITIONS		MI N <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
		Vcc=2.0V ± 0.2V	CL=30pF, RL=500		4.2		
Propagation Delay	t <sub>pd</sub>	Vcc=3. 3V ± 0. 3V	CL=50pF, RL=500		3.0		ns
		Vcc=5V ± 0.5V	CL=50pF, RL=500		3. 2		
Power dissipationCap acitance	C <sub>pd</sub>	Vcc=5V	f=10MHz		25		pF

- (1) All unused inputs of the device must be held at  $V_{\text{CC}}$  or GND to ensure proper device operation.
- (2) This parameter is ensured by design and/or characterization and is not tested in production.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

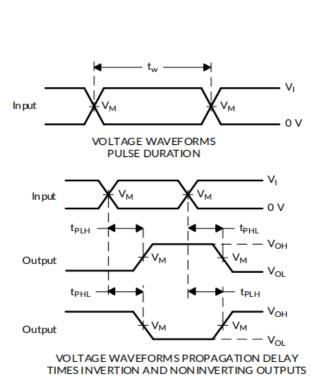


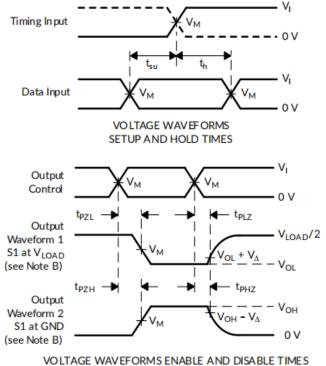
#### Parameter Measurement Information



TEST	S1
tplh/tphl	0pen
tplz/tpzl	VLOAD
tpHz/tpzH	GND

V.	INPUTS		V	V		D.	V
Vcc	Vı	tr/tf	Vm VLOAD	CL	R∟	V	
2. 0V ± 0. 2V	Vcc	≤2ns	Vcc/2	2 x Vcc	30pF	500	0. 15V
3. 3V ± 0. 3V	3V	≤2.5ns	1.5V	6V	50pF	500	0. 3V
5V ± 0.5V	Vcc	≤2.5ns	Vcc/2	2 x Vcc	50pF	500	0.3V





LOW-AND HIGH-LEVEL ENABLING

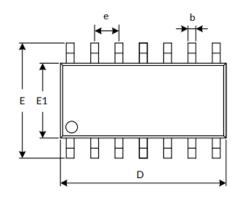
AOS4GT32

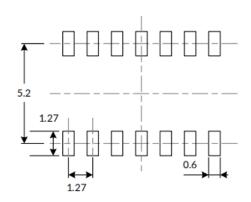
- NOTES: A. C∟includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
    Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0$  = 50 .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. tplz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

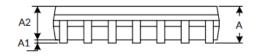


# PACKAGE OUTLINE DIMENSIONS SOP14(3)





RECOMMENDED LAND PATTERN (Unit: mm)





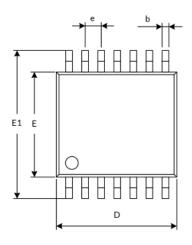
Cambal	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A <sup>(1)</sup>		1. 750		0.069	
A1	0. 100	0. 250	0.004	0.010	
A2	1.300	1.500	0. 051	0.059	
b	0.390	0. 470	0. 015	0.019	
С	0. 200	0. 240	0.008	0.009	
D <sup>(1)</sup>	8. 550	8. 750	0. 336	0.344	
е	1. 270(	(BSC) <sup>(2)</sup>	0.050(	(BSC) (2)	
Е	5.800	6. 200	0. 228	0. 244	
E1 <sup>(1)</sup>	3.800	4.000	0. 150	0. 157	
L	0.500	0.800	0.020	0.031	
	0°	8°	0°	8°	

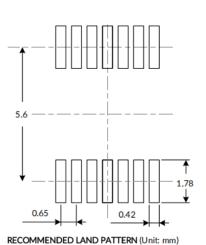
#### NOTE:

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

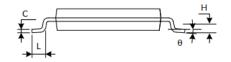


### TSS0P-14(3)







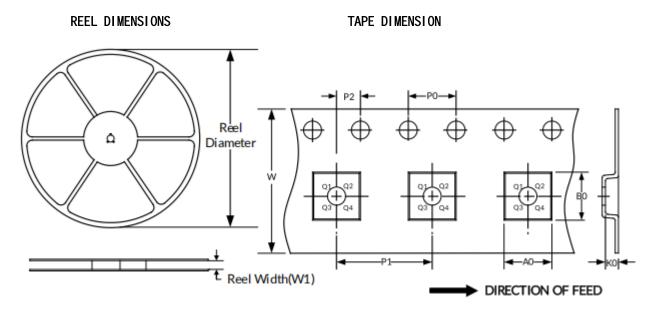


Symbol	Dimensions In	n Millimeters	Dimensions In Inches			
	Mi n	Max	Min	Max		
A <sup>(1)</sup>		1. 200		0.047		
A1	0.050	0.150	0.002	0.006		
A2	0.900	1.050	0.035	0. 041		
b	0.200	0.300	0.008	0.012		
С	0.130	0. 200	0.005	0.007		
D <sup>(1)</sup>	4.860	5. 100	0. 191	0. 201		
E <sup>(1)</sup>	4. 300	4. 500	0. 169	0.177		
E1	6. 200	6. 550	0. 244	0. 260		
е	0.650(	[BSC) (2)	0.026(BSC) <sup>(2)</sup>			
L	0.450	0.750	0.018	0.030		
Н	0. 250	(TYP)	0.010(TYP)			
	0°	8°	0°	8°		

#### NOTE:

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

#### TAPE AND REEL INFORMATION



NOTE: The picture is only for reference. Please make the object as the standard.

#### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	AO (mm)	BO (mm)	KO (mm)	PO (mm)	P1 (mm)	P2 (mm)	W (mm)	Pi n1 Quadrant
SOP14	13' '	16.4	6.60	9. 30	2. 10	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13' '	12. 4	6. 95	5.60	1. 20	4.0	8.0	2.0	12.0	Q1

#### NOTE:

- 1. All dimensions are nominal.
- 2. Plastic or metal protrusions of 0.15mm maximum per side are not included.